

# Low Power GaAs MMIC Double Balanced Mixer

# MM1-0212LSM

# 1. Device Overview

# 1.1 General Description

The MM1-0212LSM is a low power GaAs MMIC double balanced mixer that operates at LO powers as a low as +1 dBm. MM1-0212LSM is a low frequency, low power S band mixer that works well as both an up and down converter through X band. This mixer offers low conversion loss and high LO to RF isolation at extremely low LO drives. The sister MM1-0212HSM and MM1-0212SSM are recommended for high linearity applications. The MM1-0212LSM is available in a 4x4 mm QFN package. Evaluation boards are available.



QFN

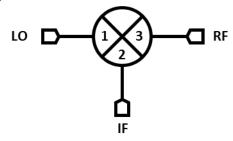
#### 1.2 Features

- Low +1 dBm minimum LO drive
- High LO to RF isolation
- RoHS Compliant

# 1.3 Applications

- Mobile test and measurement equipment
- Power efficient modules

#### 1.4 Functional Block Diagram



## 1.5 Part Ordering Options<sup>1</sup>

Part Number	Description	Package	Green Status	Product Lifecycle	Export Classification
MM1-0212LSM-2	4x4 mm QFN	SM	RoHS	Active	EAR99
EVAL-MM1-0212L	Connectorized Evaluation Fixture	Eval	кипо	Active	EAR99

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<sup>&</sup>lt;sup>1</sup> Refer to our <u>website</u> for a list of definitions for terminology presented in this table.



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# Revision History

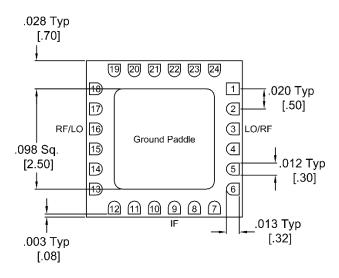
Revision Code	Revision Date	Comment
-	June 2018	Datasheet Initial Release
А	January 2019	Added max power/current spec, ESD rating



# 2. Port Configurations and Functions

# 2.1 Port Diagram

A bottom-up view of the MM1-0212LSM's SM package outline drawing is shown below. The MM1-0212LSM has the input and output ports given in Port Functions. The MM1-0212LSM can be used in either an up or down conversion. For configuration A, input the LO into pin 3, use pin 16 for the RF, and port 9 for the IF. For configuration B, input the LO into pin 16, use pin 3 for the RF, and pin 9 for the IF.



# 2.2 Port Functions

Port	Function	Description	DC Interface schematic
Pin 3	LO (Configuration A) RF (Configuration B)	Pin 3 is DC short and AC matched to 50 Ohms from 2 to 12 GHz. Blocking capacitor is optional.	P3
Pin 9	IF	Pin 9 is DC coupled to the diodes. Blocking capacitor is optional.	<b>P9</b>
Pin 16	RF (Configuration A) LO (Configuration B)	Pin 16 is DC open and AC matched to 50 Ohms from 2 to 12 GHz. Blocking capacitor is optional.	P16~
GND	Ground	SM package ground path is provided through the ground paddle.	GND∽⊒



# 3. Specifications

# 3.1 Absolute Maximum Ratings

The Absolute Maximum Ratings indicate limits beyond which damage may occur to the device. If these limits are exceeded, the device may be inoperable or have a reduced lifetime.

Parameter	Maximum Rating	Units
Pin 3 DC Current	30	mA
Pin 9 DC Current	30	mA
Power Handling, at any Port	+30	dBm
Operating Temperature	-55 to +100	°C
Storage Temperature	-65 to +125	°C

## 3.2 Package Information

Parameter	Details	Rating
ESD	Human Body Model (HBM), per MIL-STD-750, Method 1020	1A
Weight	EVAL package	13.4 g

#### 3.3 Recommended Operating Conditions

The Recommended Operating Conditions indicate the limits, inside which the device should be operated, to guarantee the performance given in Electrical Specifications Operating outside these limits may not necessarily cause damage to the device, but the performance may degrade outside the limits of the electrical specifications. For limits, above which damage may occur, see Absolute Maximum Ratings.

	Min	Nominal	Max	Units
T <sub>A</sub> , Ambient Temperature	-55	+25	+100	°C
LO Input Power	+1		+15	dBm

# 3.4 Sequencing Requirements

There is no requirement to apply power to the ports in a specific order. However, it is recommended to provide a  $50\Omega$  termination to each port before applying power. This is a passive diode mixer that requires no DC bias.



# 3.5 Electrical Specifications

The electrical specifications apply at TA= $+25^{\circ}$ C in a  $50\Omega$  system. Typical data shown is for a down conversion application with a +9dBm sine wave LO input. Specifications shown for configuration A (B).

Parameter		Test Conditions	Min	Typical	Max	Units	
RF (Pin 16) Frequency Range			2		12		
LO (Pin 3) Freque	ency Range		2		12	GHz	
I (Pin 9) Frequenc	y Range		0		3		
		RF/LO = 2 - 12 GHz I = DC - 0.2 GHz		8.5 (10)	11.5 (12.5)	-ID	
Conversion Loss (CL) <sup>2</sup>		RF/LO = 2 - 12 GHz I = 0.2 - 3 GHz		9.5 (12)		- dB	
Noise Figure (NF)	3	RF/LO = 2 - 12 GHz I = DC - 0.2 GHz		9		dB	
	LO to RF	RF/LO = 2 - 12 GHz		57			
Isolation	LO to IF	IF/LO = 2 - 12 GHz		27		dB	
RF to IF		RF/IF = 2 - 12 GHz		40			
Input IP3 (IIP3)		RF/LO = 2 - 12 GHz I = DC - 0.2 GHz		+13 (+14)		dBm	
Input 1 dB Gain C Point (P1dB)	Compression			+2 (+4)		dBm	

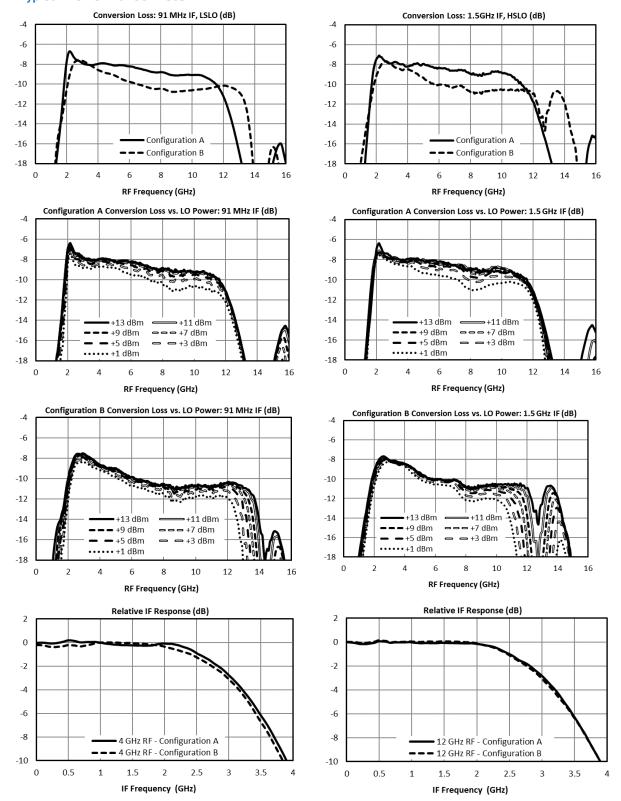
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<sup>&</sup>lt;sup>2</sup> Measured as a down converter to a fixed 91MHz IF.

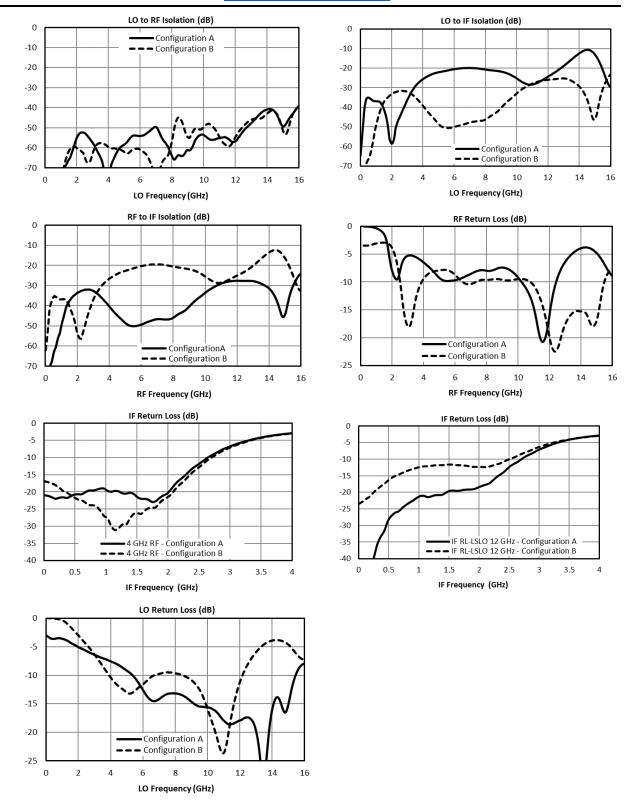
 $<sup>^{3}</sup>$  Mixer Noise Figure typically measures within 0.5 dB of conversion loss for IF frequencies greater than 5 MHz.



## 3.6 Typical Performance Plots

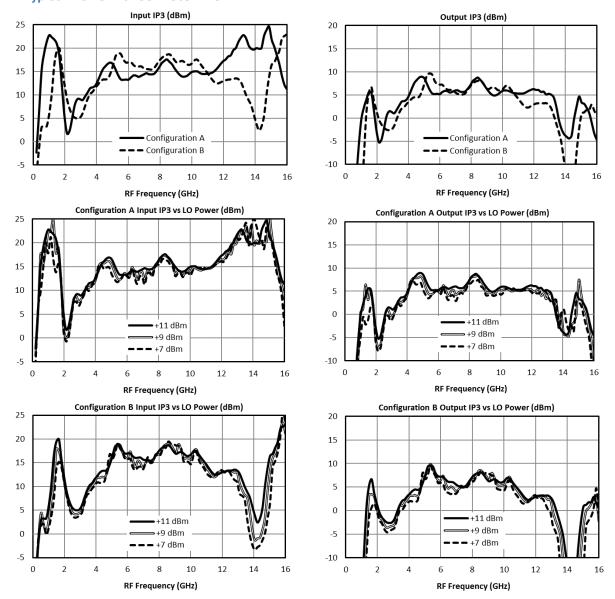






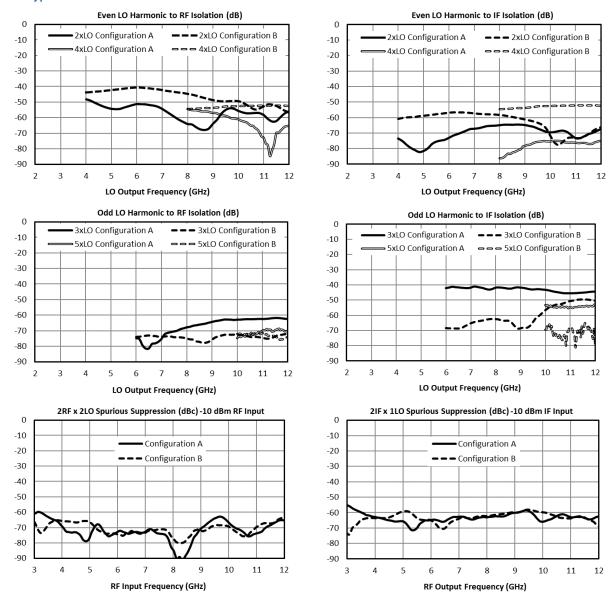


# 3.6.1 Typical Performance Plots: IP3





# 3.6.2 Typical Performance Plots: LO Harmonic Isolation





## 3.6.3 Typical Spurious Performance: Down-Conversion

Typical spurious data is provided by selecting RF and LO frequencies ( $\pm$  m\*LO  $\pm$  n\*RF) within the RF/LO bands, to create a spurious output within the IF band. The mixer is swept across the full spurious band and the mean is calculated. The numbers shown in the table below are for a -10 dBm RF input. Spurious suppression is scaled for different RF power levels by (n-1), where "n" is the RF spur order. For example, the 2RF x 2LO spur is 70 dBc for a -10 dBm input, so a -20 dBm RF input creates a spur that is (2-1) x (-10 dB) lower, or 80 dBc. Data is shown for the frequency plan in Typical Performance. mLOxORF plots can be found in section 3.6.2 Typical Performance Plots: LO Harmonic Isolation. OLOx1RF plot is identical to the plot of LO-RF isolation.

Typical Down-conversion	spurious	suppression	(dBc):	Config	Α (	B)

-10 dBm RF Input	OxLO	1xLO	2xLO	3xLO	4xLO	5xLO
OxRF	-	58 (59)	54 (47)	61 (65)	64 (52)	69 (71)
1xRF	30 (15)	Reference	37 (36)	11 (12)	42 (40)	25 (27)
2xRF	72 (72)	51 (51)	70 (69)	61 (59)	64 (65)	66 (59)
3xRF	77 (65)	41 (44)	72 (77)	55 (56)	76 (74)	54 (55)
4xRF	99 (104)	82 (88)	92 (89)	77 (80)	97 (102)	92 (93)
5xRF	99 (102)	97 (97)	95 (93)	81 (84)	104 (105)	91 (95)

## 3.6.4 Typical Spurious Performance: Up-Conversion

Typical spurious data is taken by mixing an input within the IF band, with LO frequencies ( $\pm$  m\*LO  $\pm$  n\*IF), to create a spurious output within the RF output band. The mixer is swept across the full spurious output band and the mean is calculated. The numbers shown in the table below are for a -10 dBm IF input. Spurious suppression is scaled for different IF input power levels by (n-1), where "n" is the IF spur order. For example, the 2IFx1LO spur is typically 63 dBc for a -10 dBm input with a sine-wave LO, so a -20 dBm IF input creates a spur that is (2-1) x (-10 dB) lower, or 73 dBc. Data is shown for the frequency plan in Typical Performance.

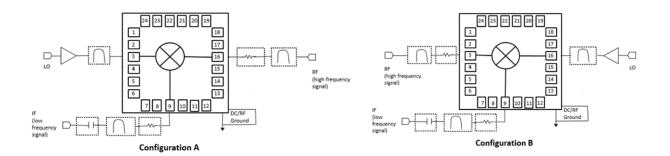
Typical Up-conversion spurious suppression (dBc): Config A (B)

-10 dBm IF Input	OxLO	1xLO	2xLO	3xLO	4xLO	5xLO
OxIF	-	88 (87)	68 (60)	43 (61)	79 (73)	53 (73)
1xIF	29 (21)	Reference	40 (39)	11 (13)	47 (42)	23 (25)
2xIF	53 (67)	63 (61)	57 (55)	59 (68)	59 (56)	69 (67)
3xIF	87 (74)	52 (53)	64 (66)	41 (46)	66 (70)	55 (49)
4xIF	108 (113)	111 (113)	97 (93)	97 (104)	98 (88)	104 (104)
5xIF	121 (121)	101 (104)	117 (116)	85 (86)	108 (113)	97 (87)



# 4. Operation

## 4.1 Application Circuit



#### 4.2 Ports Operation

**IF Port** — Used as input on an upconversion, output on downconversion, or LO port in a band shifting application. Signals should be connected by 50 ohm microstrip or coplanar traces to well matched broadband 50 ohm sources and loads. Blocking capacitor is recommended if DC voltage is present on the line.

**RF Port** — Used as input on a downconversion, output on upconversion, or output in a band shifting application. Signals should be connected by 50 ohm microstrip or coplanar traces to well matched broadband 50 ohm sources and loads.

**Filtering and Matching**- Filtering is generally desired for spurious and image removal on the output port of the mixer. Reflective filters can cause out of band signals to reflect back into the mixer and cause conversion loss ripple, erroneous spurs, and other undesired behaviors. To eliminate these problems it is recommend that the filters be placed as close to the output port as possible. If undesired behavior is still observed, a diplexer with one port terminated or a 1-3 dB attenuator may reduce this problem.

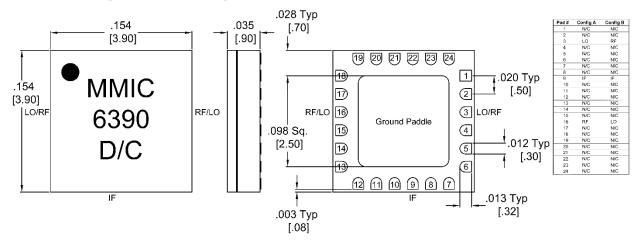
**RF Ground** — The ground paddle of the QFN should be connected to a low noise RF ground with very low electrical resistance for high frequency operation.

**LO Port** — The noise floor of the LO input signal should be less than the value of the noise floor plus isolation of the mixer, or a filter is recommended to prevent reduction in dynamic range. An LO amplifier is required if the LO power is below the recommended drive level. It is important to use an amplifier with a broadband 50 ohm match such that it does not reflect spurious signals back into the mixer or other system circuitry.



# 5. Mechanical Data

# 5.1 SM Package Outline Drawing



- 1. Substrate material is ceramic.
- 2. I/O Leads and Ground Paddle plating is (from base to finish):

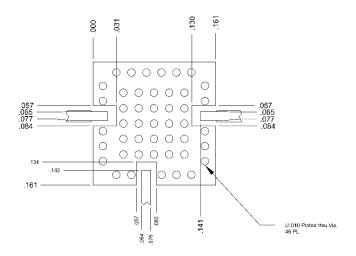
 Ni:
 8.89um MAX
 1.27um MIN

 Pd:
 0.17um MAX
 0.07um MIN

 Au
 0.254um MAX
 0.03um MIN

3. All unconnected pads should be connected to PCB RF ground.

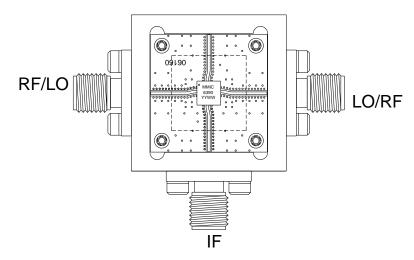
## 5.2 SM Package Footprint



QFN-Package Surface-Mount Landing Pattern
Click here for a DXF of the above layout.
Click here for leaded solder reflow. Click here for lead-free solder reflow.



# 5.3 Evaluation Board Outline Drawing



Configuration A	Configuration B	Connector Type
RF	LO	SMA Female
LO	RF	SMA Female
IF	IF	SMA Female
Note: Eval connectors are not removeable		

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